

Keyboard Encoder

FEATURES

- One integrated circuit required for complete keyboard assembly
- Outputs directly compatible with TTL/DTL or MOS logic arrays
- External control provided for output polarity selection
- External control provided for selection of odd or even parity
- Two key roll-over operation
- N-key lockout
- Programmable coding with a single mask change
- Self-contained oscillator circuit
- Externally controlled delay network provided to eliminate the effect of contact bounce
- Static charge protection on all input and output terminals
- Entire circuit protected by a layer of glass passivation

DESCRIPTION

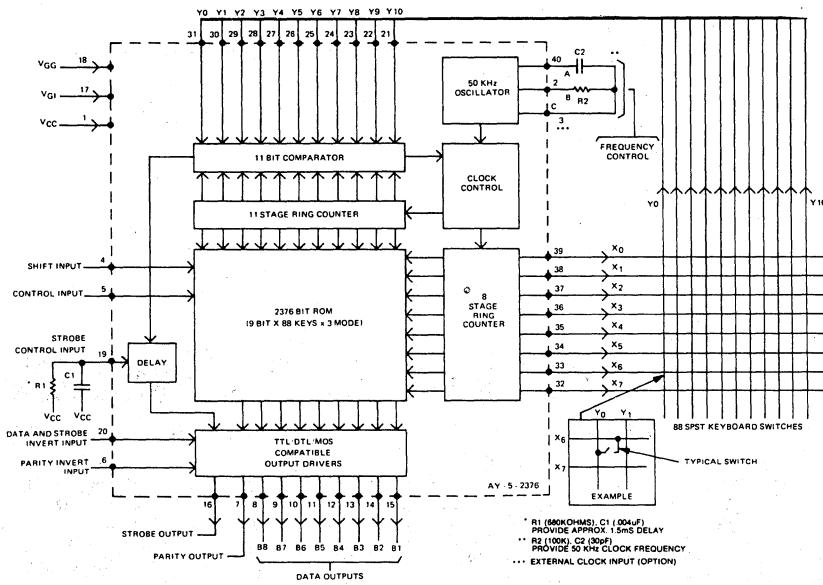
The General Instrument AY-5-2376 is a 2376 Bit Read Only Memory with all the logic necessary to encode single pole single throw keyboard closures into a usable 9-bit code. Data and strobe outputs are directly compatible with TTL/DTL or MOS logic arrays without the use of any special interface components.

The AY-5-2376 is fabricated with MTNS technology and contains 2942 P-channel enhancement mode transistors on a single monolithic chip.

PIN CONFIGURATION 40 LEAD DUAL IN LINE

Top View	
V _{CC}	1
Frequency Control B	2
Frequency Control C	3
Shift Input	4
Control Input	5
Parity Invert Input	6
Parity Output	7
Data Output B8	8
Data Output B7	9
Data Output B6	10
Data Output B5	11
Data Output B4	12
Data Output B3	13
Data Output B2	14
Data Output B1	15
Strobe Output	16
V _{G1}	17
V _{G2}	18
Strobe Control Input	19
Data & Strobe Invert Input	20
40	Frequency Control A
39	X0
38	X1
37	X2
36	X3
35	X4
34	X5
33	X6
32	X7
31	Y0
30	Y1
29	Y2
28	Y3
27	Y4
26	Y5
25	Y6
24	Y7
23	Y8
22	Y9
21	Y10
	Keyboard Matrix Outputs
	Keyboard Matrix Inputs

BLOCK DIAGRAM



OPERATION

The AY-5-2376 contains (see Block Diagram) a 2376-bit ROM, 8-stage and 11-stage ring counters, an 11-bit comparator, an oscillator circuit, an externally controllable delay network for eliminating the effect of contact bounce, and TTL/DTL/MOS compatible output drivers.

The ROM portion of the chip is a 264 by 9 bit memory arranged into three 88-word by 9-bit groups. The appropriate levels on the Shift and Control Inputs selects one of the three 88-word groups; the 88-individual word locations are addressed by the two ring counters. Thus, the ROM address is formed by combining the Shift and Control Inputs with the two ring counters.

The external outputs of the 8-stage ring counter and the external inputs to the 11-bit comparator are wired to the keyboard to form an X-Y matrix with the 88-keyboard switches as the crosspoints. In the standby condition, when no key is depressed, the two ring counters are clocked and sequentially address the ROM; the absence of a Strobe Output indicates that the Data Outputs are 'not valid' at this time.

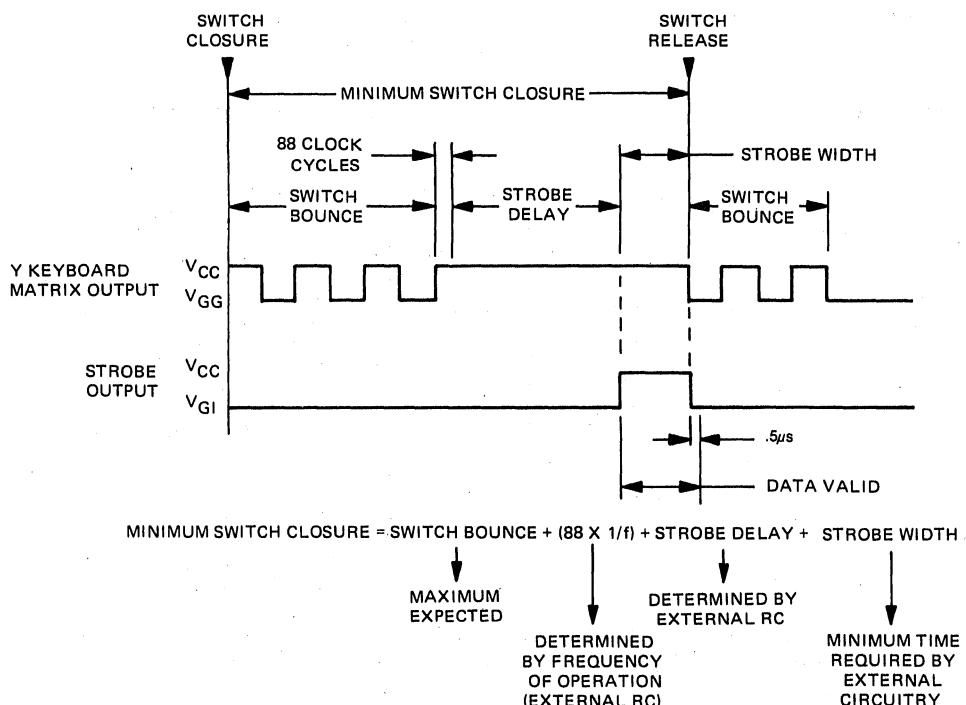
When a key is depressed, a single path is completed between one output of the 8-stage ring counter (X_0 thru X_7) and one input of the 11-bit comparator (Y_0 - Y_{10}). After a number of clock cycles, a condition will occur where a level on the selected path to the comparator matches a level on the corresponding comparator

input from the 11-stage ring counter. When this occurs, the comparator generates a signal to the clock control and 9, the Strobe Output (via the delay network). The clock control stops the clocks to the ring counters and the Data Outputs (B1-B9) stabilize with the selected 9-bit code, indicated by a 'valid' signal on the Strobe Output. The Data Outputs remain stable until the key is released.

As an added feature two inputs are provided for external polarity control of the Data Outputs. Parity Invert (pin 6) provides polarity control of the Parity Output (pin 7) while the Data and Strobe Invert Input (pin 20) provides for polarity control of Data Outputs B1 thru B8 (pins 8 thru 15) and the Strobe Output (pin 16).

ROM

TIMING DIAGRAM



ELECTRICAL CHARACTERISTICS

Maximum Ratings

V_{GI} and V_{GG} (with respect to V_{CC}) -20V to +0.3V
 Logic input voltages (with respect to V_{CC}) -20V to +0.3V
 Storage Temperature -65°C to +150°C
 Operating Temperature Range 0°C to +70°C

*Exceeding these ratings could cause permanent damage.
 Functional operation of this device at these conditions is not implied—operating ranges are specified below.

Standard Conditions (unless otherwise noted)

 $V_{CC} = +5$ Volts ± 0.5 Volts, $V_{GG} = -12$ Volts ± 1.0 Volts, $V_{GI} = GND$. $(V_{CC} = \text{Substrate Voltage})$ Operating Temperature (T_A) = 0°C to +70°C

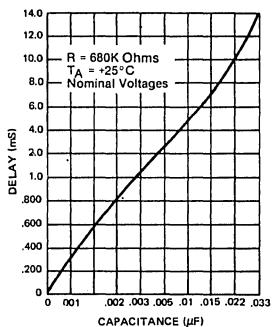
Characteristics	Sym	Min	Typ**	Max	Units	Conditions
Clock Frequency	f	10	50	100	KHz	See Block diagram footnote** for typical R - C values
Data Input (Shift, Control, Parity invert, data & strobe invert).						
Logic "0" Level	V_{10}	V_{GG}	—	+0.8	V	
Logic "1" Level	V_{11}	$V_{CC}-1.5$	—	$V_{CC}+0.3$	V	
Shift & Control Input Current	$I_{INS,C}$	15 8	36 16	60 30	μA	$V_I=+5V$ $V_I=0V$
Data, Parity Invert Input Current	$I_{IND,P}$	—	.01	1	μA	$V_I=-5V$ to +5V
X Output (X_0-X_7)						
Logic "1" Output Current	I_{X1}	— 80 140 250 500	0 150 300 700 1500	— 400 800 1500 3000	μA	$V_{OUT}=V_{CC}$ $V_{OUT}=V_{CC}-1.3V$ $V_{OUT}=V_{CC}-2.0V$ $V_{OUT}=V_{CC}-5V$ $V_{OUT}=V_{CC}-10V$
Logic "0" Output Current	I_{X0}	15 13 12 5 —	30 27 25 10 1	80 65 60 40 20	μA	$V_{OUT}=V_{CC}$ $V_{OUT}=V_{CC}-1.3V$ $V_{OUT}=V_{CC}-2.0V$ $V_{OUT}=V_{CC}-5V$ $V_{OUT}=V_{CC}-10V$
Y Input (Y_0-Y_{10})						
Trip Level	V_Y	$V_{CC}-5$	$V_{CC}-3$	$V_{CC}-2$	V	Y Input Going Positive
Hysteresis	ΔV_Y	.5	.9	1.4	V	Note 1 Note 2
Selected Y Input Current	I_{YS}	30 26 24 10 —	60 54 50 20 2	160 130 120 80 20	μA	$V_{IN}=V_{CC}$ $V_{IN}=V_{CC}-1.3V$ $V_{IN}=V_{CC}-2.0V$ $V_{IN}=V_{CC}-5V$ $V_{IN}=V_{CC}-10V$
Unselected Y Input Current	I_{YU}	15 13 12 5 —	30 27 25 10 2	80 65 60 40 20	μA	$V_{IN}=V_{CC}$ $V_{IN}=V_{CC}-1.3V$ $V_{IN}=V_{CC}-2.0V$ $V_{IN}=V_{CC}-10V$
Input Capacitance	C_{IN}	—	3	10	pF	at 0V
Switch Characteristics						See Timing Diagram
Minimum Switch Closure Contact Closure Resistance	Z_{CC} Z_{CO}	— 1×10^7	—	300	Ω	
Strobe Delay						
Trip Level (Pin 19)	V_{SD}	$V_{CC}-4$	$V_{CC}-3$	$V_{CC}-2$	V	
Hysteresis	V_{SD}	.5	.9	1.4	V	See Note 1
Quiescent Voltage (Pin 19)		-3	-5	-8	V	With 680K _L to V_{SS}
Data Output (B_1-B_9)						
Logic "0"	—	—	—	0.4	V	$I_{OL}=1.6ma$
Logic "1"	—	$V_{CC}-1$	—	—	V	$I_{OH}=100\mu A$
Power						
I_{CC}	—	—	5	10	mA	$V_{CC}=+5V$
I_{GG}	—	—	5	10	mA	$V_{GG}=-12V$

**Typical values at +25°C and nominal voltages.

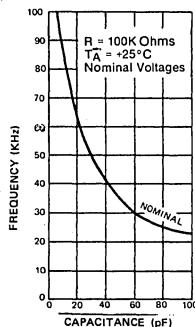
NOTE 1. Hysteresis is defined as the amount of return required to unlatch an input.

2. Guaranteed number of X & Y loads which may be applied to an X output = eleven.

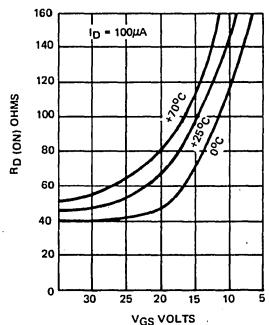
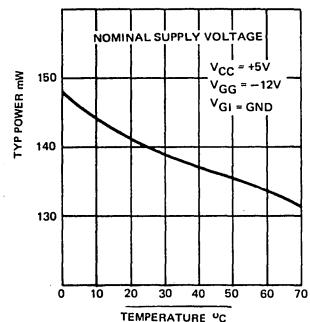
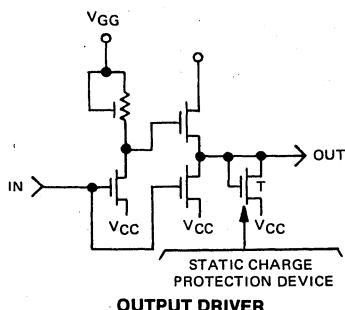
TYPICAL CHARACTERISTIC CURVES



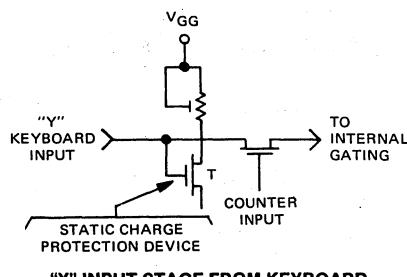
STROBE DELAY C1



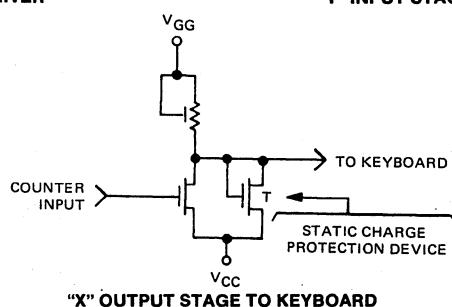
OSCILLATOR FREQUENCY VS. C2

TYPICAL OUTPUT ON RESISTANCE ($R_{D(on)}$) VS. GATE BIAS VOLTAGE (V_{GS})TYPICAL POWER CONSUMPTION (mW) VS. TEMP ($^\circ\text{C}$)

OUTPUT DRIVER



"Y" INPUT STAGE FROM KEYBOARD



"X" OUTPUT STAGE TO KEYBOARD

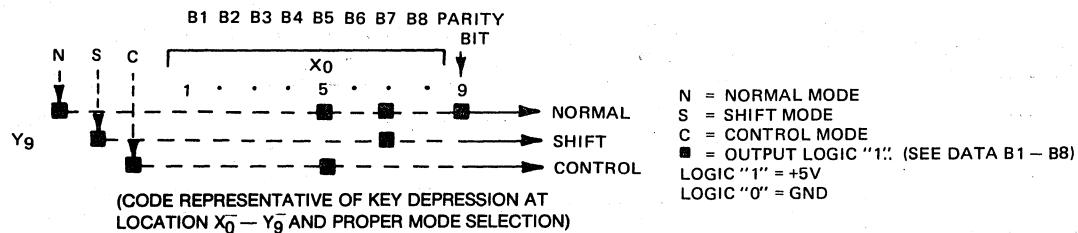
STANDARD CODE ASSIGNMENT CHART

	NSC	X ₀	X ₁	X ₂	X ₃	X ₄	X ₅	X ₆	X ₇	X ₈	X ₉
Y ₀		NULL									
Y ₁		ESC	DEL	BS	HT	LF	CR	SO	SI	DC1	DC2
Y ₂		ETB	ETX	ETZ	RS	FS	GS	US	US	DC3	DC4
Y ₃		ETB	ETX	ETZ	RS	FS	GS	US	US	DC3	DC4
Y ₄		ENQ									
Y ₅		SYN									
Y ₆		SYN									
Y ₇		SYN									
Y ₈		CAN	CAN	CAN	CAN	SP	SP	CR	CR	DC1	DC2
Y ₉		DEL	VT	FS							

Illustrated using a Logic "0" on the Data and Strobe Invert Input (Pin 20) and the Parity Invert Input (Pin 6).

NOTE 1: This code is an 8 bit ASCII code (B1-B8). Output B9 is included as an odd parity bit operating on outputs B1-B7.

*EXAMPLE



TRUTH TABLES

DATA (B1-B8) INVERT TRUTH TABLE

DATA AND STROBE INVERT INPUT (PIN 20)	CODE ASSIGNMENT CHART	DATA OUTPUTS (B1-B8)
1	1	0
0	1	1
1	0	1
0	0	0

PARITY INVERT TRUTH TABLE

PARITY INVERT INPUT (PIN 6)	CODE ASSIGNMENT CHART	PARITY OUTPUT (PIN 7)
1	1	0
0	1	1
1	0	1
0	0	0

STROBE INVERT TRUTH TABLE

DATA AND STROBE INVERT INPUT (PIN 20)	INTERNAL STROBE	STROBE OUTPUT (PIN 16)
1	1	0
0	0	0
1	0	1
0	1	1

MODE SELECTION

$\overline{S} \overline{C}$ = N
 $S \overline{C}$ = S
 $S C$ = C
 $\overline{S} C$ = C